

X3-Class HiPERFET™ **Power MOSFET**

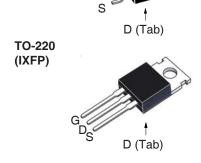
IXFA44N25X3 IXFP44N25X3

= 250V**44A** $40 \text{m}\Omega$

N-Channel Enhancement Mode Avalanche Rated



G S



G = Gate	D	=	Drain
S = Source	Tab	=	Drain

Symbol	Test Conditions	Maximum Ra	atings
V _{DSS}	$T_{_{\rm J}}$ = 25°C to 150°C	250	V
$\mathbf{V}_{\mathtt{DGR}}$	$T_{_{\mathrm{J}}} = 25^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}, R_{_{\mathrm{GS}}} = 1\text{M}\Omega$	250	V
V _{GSS}	Continuous	±20	V
V _{GSM}	Transient	±30	V
I _{D25}	T _C = 25°C	44	Α
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	66	Α
I _A	T _c = 25°C	22	A
E _{as}	$T_{c} = 25^{\circ}C$	400	mJ
dv/dt	$I_{S} \leq I_{DM}, V_{DD} \leq V_{DSS}, T_{J} \leq 150^{\circ}C$	50	V/ns
P_{D}	T _C = 25°C	240	W
T _J		-55 +150	°C
T _{JM}		150	°C
T _{stg}		-55 +150	°C
T _L	Maximum Lead Temperature for Soldering	300	°C
T _{SOLD}	1.6 mm (0.062in.) from Case for 10s	260	°C
F _c	Mounting Force (TO-263) Mounting Torque (TO-220)	1065 / 2.214.6 1.13 / 10	N/lb Nm/lb.in
Weight	TO-263 TO-220	2.5 3.0	g g

Features

TO-263 (IXFA)

- International Standard Packages
- Low $R_{DS(ON)}$ and Q_G • Avalanche Rated
- Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

Symbol (T _J = 25°C, U	Test Conditions Unless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max.
BV _{DSS}	$V_{GS} = 0V, I_D = 1mA$	250		V
$V_{\rm GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 1 \text{mA}$	2.5		4.5 V
l _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100 nA
l _{DSS}	$V_{DS} = V_{DSS}$, $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			15 μA 500 μA
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$		31	40 mΩ



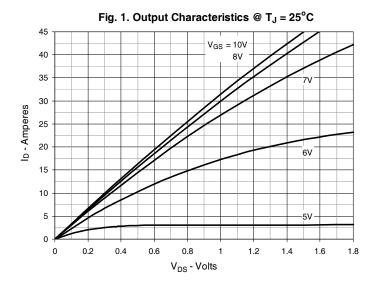
Symbol	Test Conditions	Characteristic V		Values
$(T_J = 25^{\circ}C, l)$	Unless Otherwise Specified)	Min.	Тур.	Max
g _{fs}	V _{DS} = 10V, I _D = 0.5 • I _{D25} , Note 1	22	36	S
R _{Gi}	Gate Input Resistance		2.1	Ω
C _{iss}			2200	pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		405	pF
C _{rss}			1	pF
	Effective Output Capacitance			
$C_{o(er)}$	Energy related $\int V_{GS} = 0V$		155	pF
$C_{o(tr)}$	Time related $\int V_{DS}^{GS} = 0.8 \cdot V_{DSS}$		615	pF
t _{d(on)}	Resistive Switching Times		18	ns
t,	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{DSS}$		23	ns
t _{d(off)}	$R_{\rm G} = 100$ (External)		54	ns
t _f	N _G = 1032 (External)		12	ns
$Q_{g(on)}$			33	nC
Q _{gs}	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_D = 0.5 \cdot I_{D25}$		9	nC
\mathbf{Q}_{gd}			10	nC
R _{thJC}				0.52 °C/W
R _{thCS}	TO-220		0.50	°C/W

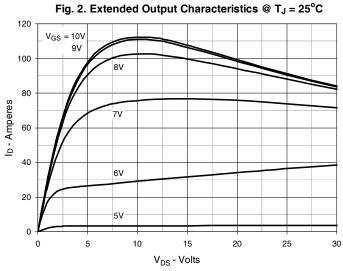
Source-Drain Diode

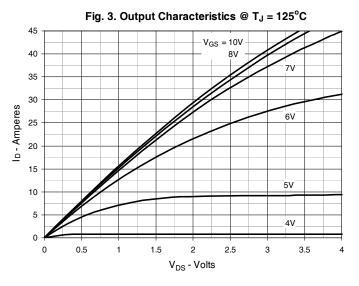
Symbol $(T_J = 25^{\circ}C, U)$	Test Conditions Unless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max	
I _s	$V_{GS} = 0V$			44	Α
I _{SM}	Repetitive, Pulse Width Limited by $\mathrm{T}_{_{\mathrm{JM}}}$			176	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.4	V
$\left. egin{array}{c} \mathbf{t}_{rr} & \\ \mathbf{Q}_{RM} & \\ \mathbf{I}_{RM} & \end{array} ight. ight.$	$I_F = 22A$, -di/dt = 100A/ μ s $V_R = 100V$		87 300 7		ns nC A

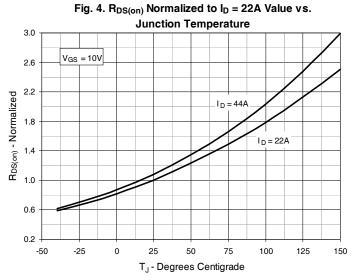
Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

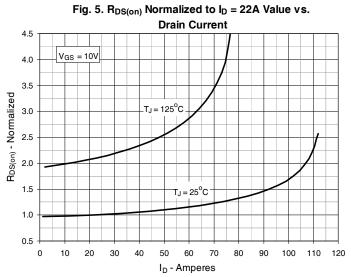


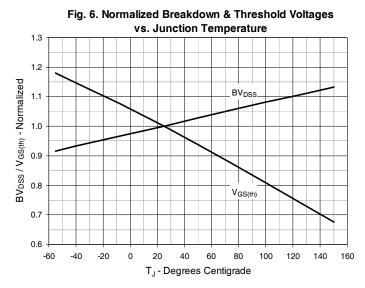




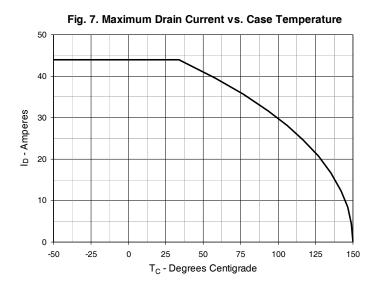


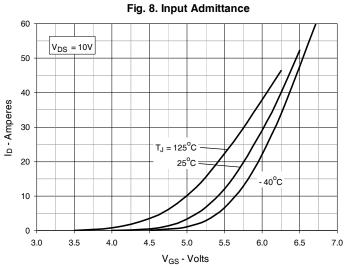


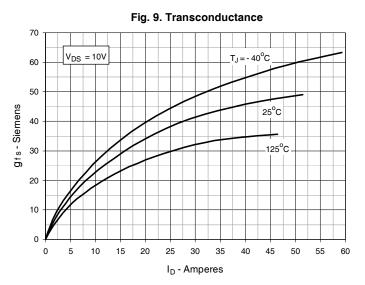


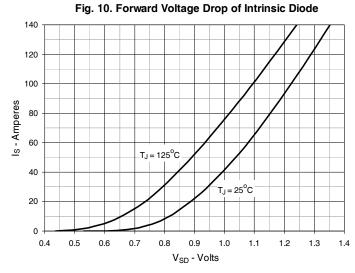


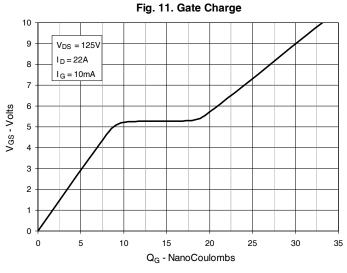


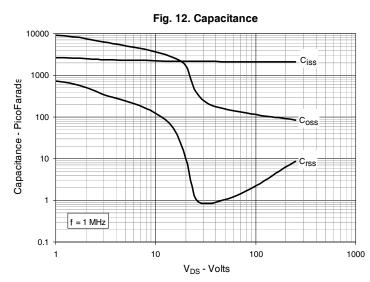












IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.



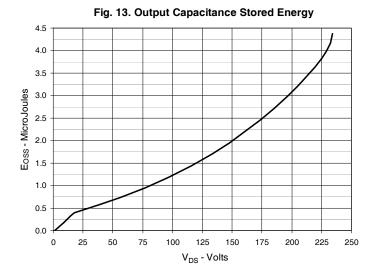
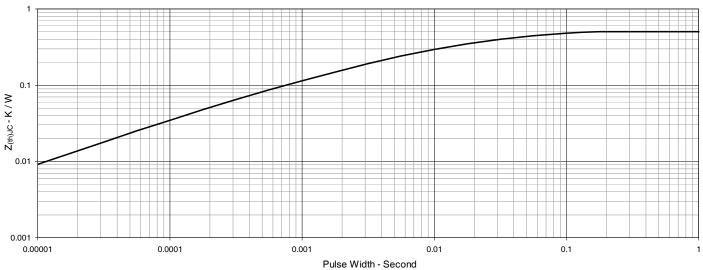
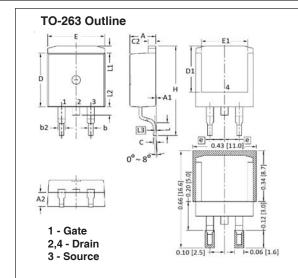


Fig. 14. Forward-Bias Safe Operating Area 100 R_{DS(on)} Limit 25µs 10 100µs ID - Amperes $T_J = 150^{\circ}C$ 0.1 10ms $T_{\rm C} = 25^{\rm o}{\rm C}$ DC Single Pulse 0.01 10 100 1,000 $V_{\rm DS}$ - Volts

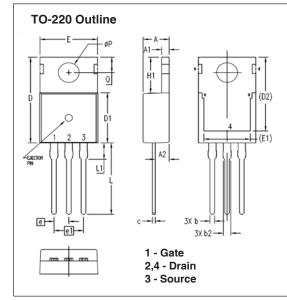
Fig. 15. Maximum Transient Thermal Impedance







CVM	INCHES		CYM — — — — — — — — — — — — — — — — — — —		MILLIN	METER
SIM	MIN	MAX	MIN	MAX		
Α	.170	.185	4.30	4.70		
A1	.000	.008	0.00	0.20		
A2	.091	.098	2.30	2.50		
b	.028	.035	0.70	0.90		
b2	.046	.060	1.18	1.52		
С	.018	.024	0.45	0.60		
C2	.049	.060	1.25	1.52		
D	.340	.370	8.63	9.40		
D1	.300	.327	7.62	8.30		
E	.380	.410	9.65	10.41		
E1	.270	.330	6.86	8.38		
е	.100	BSC	2.54	BSC		
Н	.580	.620	14.73	15.75		
L	.075	.105	1.91	2.67		
L1	.039	.060	1.00	1.52		
L2	_	.070	_	1.77		
L3	.010	BSC	0.254	BSC		



SYM	INCHES		MILLIMETERS	
2114	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.047	.055	1.20	1.40
A2	.079	.106	2.00	2.70
Ь	.024	.039	0.60	1.00
b2	.045	.057	1.15	1.45
С	.014	.026	0.35	0.65
D	.587	.626	14.90	15.90
D1	.335	.370	8.50	9.40
(D2)	.500	.531	12.70	13.50
E	.382	.406	9.70	10.30
(E1)	.283	.323	7.20	8.20
е	.100 BSC		2.54	BSC
e1	.200	BSC	5.08	BSC
H1	.244	.268	6.20	6.80
L	.492	.547	12.50	13.90
L1	.110	.154	2.80	3.90
ØΡ	.134	.150	3.40	3.80
Q	.106	.126	2.70	3.20





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